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Applications of "<u>Embedded - Microcontrollers</u>"

Details	
Product Status	Obsolete
Core Processor	Z8
Core Size	8-Bit
Speed	12MHz
Connectivity	-
Peripherals	POR, WDT
Number of I/O	14
Program Memory Size	2KB (2K x 8)
Program Memory Type	OTP
EEPROM Size	-
RAM Size	125 x 8
Voltage - Supply (Vcc/Vdd)	4.5V ~ 5.5V
Data Converters	-
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	20-SSOP (0.209", 5.30mm Width)
Supplier Device Package	-
Purchase URL	https://www.e-xfl.com/product-detail/zilog/z86e0812hec1866tr

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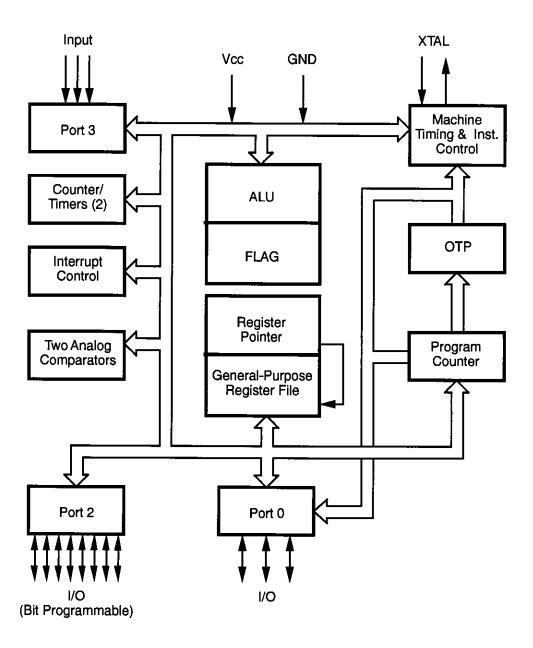


Figure 1. Functional Block Diagram

GENERAL DESCRIPTION (Continued)

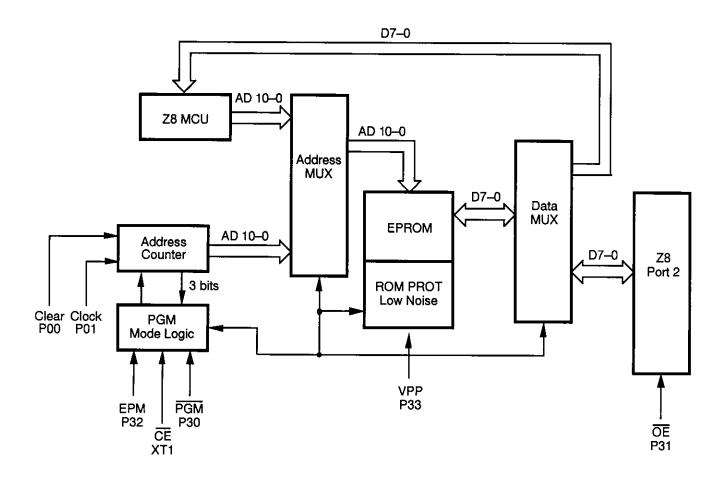


Figure 2. EPROM Programming Mode Block Diagram

PIN DESCRIPTION

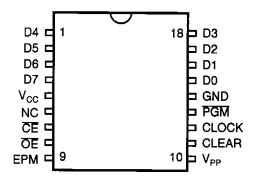


Figure 3. 18-Pin EPROM Mode Configuration

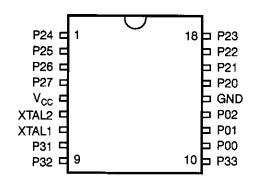


Figure 4. 18-Pin DIP/SOIC Mode Configuration

Table 1. 18-Pin DIP Pin Identification

EPROM	Programmi	ng Mode	
Pin#	Symbol	Function	Direction
1–4	D4-D7	Data 4, 5, 6, 7	In/Output
5	V _{cc}	Power Supply	
6	NC	No Connection	
7	CE	Chip Enable	Input
8	ŌĒ	Output Enable	Input
9	EPM	EPROM Prog Mode	Input
10	V _{PP}	Prog Voltage	Input
11	Clear	Clear Clock	Input
12	Clock	Address	Input
13	PGM	Prog Mode	Input
14	GND	Ground	·
15–18	D0-D3	Data 0,1, 2, 3	In/Output

Table 2. 18-Pin DIP/SOIC Pin Identification

Standa	rd Mode		
Pin#	Symbol	Function	Direction
1–4	P24-P27	Port 2, Pins 4,5,6,7	In/Output
5	V _{CC}	Power Supply	<u></u>
6	XTAL2	Crystal Osc. Clock	Output
7	XTAL1	Crystal Osc. Clock	Input
8	P31	Port 3, Pin 1, AN1	Input
9	P32	Port 3, Pin 2, AN2	Input
10	P33	Port 3, Pin 3, REF	Input
11–13	P00-P02	Port 0, Pins 0,1,2	In/Output
14	GND	Ground	
15–18	P20-P23	Port 2, Pins 0,1,2,3	In/Output

STANDARD TEST CONDITIONS

The characteristics listed below apply for standard test conditions as noted. All voltages are referenced to Ground. Positive current flows into the referenced pin (Figure 5).

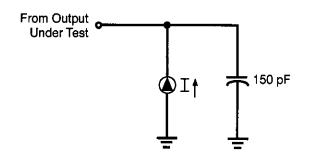


Figure 5. Test Load Diagram

CAPACITANCE

 $T_A = 25$ °C, $V_{CC} = GND = 0V$, f = 1.0 MHz, unmeasured pins returned to GND.

Parameter	Min	Max
Input capacitance	0	10 pF
Output capacitance	0	20 pF
I/O capacitance	0	25 pF

			$T_A = 0^{\circ}C$	to +70°C	Typical			·
Sym	Parameter	V _{CC} [4]	Min	Max	@ 25°C	Units	Conditions	Notes
Icc	Supply Current	4.5V		11.0	6.8	mA	All Output and I/O Pins Floating @ 2 MHz	5,7
		5.5V		11.0	6.8	mA	All Output and I/O Pins Floating @ 2 MHz	5,7
		4.5V		15.0	8.2	mA	All Output and I/O Pins Floating @ 8 MHz	5,7
		5.5V		15.0	8.2	mA	All Output and I/O Pins Floating @ 8 MHz	5,7
		4.5V	•	20.0	12.0	mA	All Output and I/O Pins Floating @ 12 MHz	5,7
		5.5V		20.0	12.0	mA	All Output and I/O Pins Floating @ 12 MHz	5,7
l _{CC1}	Standby Current	4.5V		4.0	2.5	mA	HALT Mode V _{IN} = 0V, V _{CC} @ 2 MHz	5,7
		5.5V	~	4.0	2.5	mA	HALT Mode V _{IN} = 0V, V _{CC} @ 2 MHz	5,7
		4.5V	.,	5.0	3.0	mA	HALT Mode V _{IN} = 0V, V _{CC} @ 8 MHz	5,7
		5.5V	-	5.0	3.0	mA	HALT Mode V _{IN} = 0V, V _{CC} @ 8 MHz	5,7
		4.5V		7.0	4.0	mA	HALT Mode V _{IN} = 0V, V _{CC} @ 12 MHz	5,7
		5.5V		7.0	4.0	mA	HALT Mode V _{IN} = 0V, V _{CC} @ 12 MHz	5,7
I _{cc}	Supply Current (Low Noise Mode)	4.5V		11.0	6.8	mA	All Output and I/O Pins Floating @ 1 MHz	7
		5.5V		11.0	6.8	mA	All Output and I/O Pins Floating @ 1 MHz	7
		4.5V		13.0	7.5	mA	All Output and I/O Pins Floating @ 2 MHz	7
		5.5V		13.0	7.5	mA	All Output and I/O Pins Floating @ 2 MHz	7
		4.5V		15.0	8.2		All Output and I/O Pins Floating @ 4 MHz	7
		5.5V		15.0	8.2	mA	All Output and I/O Pins Floating @ 4 MHz	7

DC ELECTRICAL CHARACTERISTICS

Extended Temperature

		T _A = -40°C to +105°C		Typical				
Sym	Parameter	V _{cc} [4]	Min	Max	@ 25°C	Units	Conditions	Notes
$\overline{V_{\text{INMAX}}}$	Max Input Voltage	4.5V		12.0		V	I _{IN} < 250 μA	1
		5.5V	**	12.0	 	V	I _{IN} < 250 μA	1
V _{CH}	Clock Input High Voltage	4.5V	0.8 V _{CC}	V _{CC} +0.3	2.8	V	Driven by External Clock Generator	
		5.5V	0.8 V _{CC}	V _{CC} +0.3	2.8	٧	Driven by External Clock Generator	
V _{CL}	Clock Input Low Voltage	4.5V	V _{SS} -0.3	0.2 V _{CC}	1.7	٧	Driven by External Clock Generator	
		5.5V		0.2 V _{CC}	1.7	V	Driven by External Clock Generator	
V _{IH}	Input High Voltage	4.5V	0.7 V _{CC}	V _{CC} +0.3	2.8	V		
		5.5V	0.7 V _{CC}	V _{CC} +0.3	2.8	٧	**	
V_{IL}	Input Low Voltage	4.5V	V _{ss} –0.3	0.2 V _{CC}	1.5	V		
		5.5V	V _{ss} -0.3	0.2 V _{CC}	1.5	V		
V_{OH}	Output High Voltage	4.5V	V _{CC} -0.4		4.8	V	I _{OH} = -2.0 mA	5
	-	5.5V	V _{CC} -0.4		4.8	V	I _{OH} = -2.0 mA	5
		4.5V	V _{CC} -0.4	<u> </u>		٧	Low Noise @ I _{OH} = -0.5 mA	
		5.5V	V _{CC} -0.4	•	**	V	Low Noise @ I _{OH} = -0.5 mA	
V _{OL1}	Output Low Voltage	4.5V		0.4	0.1	V	$I_{OL} = +4.0 \text{ mA}$	5
	•	5.5V		0.4	0.1	٧	$I_{OL} = +4.0 \text{ mA}$	5
		4.5V		0.4	0.1	٧	Low Noise @ I _{OL} = 1.0 mA	
	•	5.5V		0.4	0.1	V	Low Noise @ I _{OL} = 1.0 mA	
V _{OL2}	Output Low Voltage	4.5V		1.0	0.3	V	I _{OL} = +12 mA,	5
		5.5V		1.0	0.3	V	$I_{OL} = +12 \text{ mA},$	5
V_{OFFSET}	Comparator Input	4.5V		25.0	10.0	mV		
	Offset Voltage	5.5V		25.0	10.0	mV		
V _{LV}	V _{CC} Low Voltage Auto Reset		1.8	3.8	2.8	V	@ 6 MHz Max. Int. CLK Freq.	3
l _{i∟}	Input Leakage	4.5V		-1.0	1.0	μА	$V_{IN} = 0V, V_{CC}$	
	(Input Bias Current of Comparator)	5.5V		-1.0	1.0	μА	$V_{IN} = 0V$, V_{CC}	
I _{OL}	Output Leakage	4.5V		-1.0	1.0	μА	$V_{IN} = 0V_i V_{CC}$	
		5.5V		-1.0	1.0	μA	$V_{IN} = 0V, V_{CC}$	
V _{ICR}	Comparator Input Common Mode Voltage Range		Ö	V _{CC} –1.5		V		· . <u></u>

Sym	Parameter	V _{cc} [4]	T _A = -40°C to +105°C Min Max	Typical @ 25°C	Units	Conditions	Notes
I _{CC1}	Standby Current (Low Noise Mode)	4.5V	4.0	2.5	mA	HALT Mode V _{IN} = 0V, V _{CC} @ 1 MHz	7
		5.5V	4.0	2.5	mA	HALT Mode V _{IN} = 0V, V _{CC} @ 1 MHz	7
		4.5V	4.5	2.8	mA	HALT Mode V _{IN} = 0V, V _{CC} @ 2 MHz	7
		5.5V	4.5	2.8	mA	HALT Mode V _{IN} = 0V, V _{CC} @ 2 MHz	7
		4.5V	5.0	3.0	mA	HALT Mode V _{IN} = 0V, V _{CC} @ 4 MHz	7
		5.5V	5.0	3.0	mA	HALT Mode V _{IN} = 0V, V _{CC} @ 4 MHz	7
I _{CC2}	Standby Current	4.5V	20	1.0	μА	STOP Mode $V_{IN} = 0V, V_{CC}$ WDT is not Running	7,8
		5.5V	20	1.0	μА	STOP Mode V _{IN} = 0V, V _{CC} WDT is not Running	7,8
I _{ALL}	Auto Latch Low	4.5V	40	16	μА	OV < V _{IN} < V _{CC}	
	Current	5.5V	40	16	μА	OV < V _{IN} < V _{CC}	
I _{ALH}	Auto Latch High	4.5V	-20.0	-8.0	μА	OV < V _{IN} < V _{CC}	
	Current	5.5V	-20.0	-8.0	μА	0V < V _{IN} < V _{CC}	

Notes:

- 1. Port 2 and Port 0 only
- 2. $V_{SS} = 0V = GND$
- 3. The device operates down to V_{LV} of the specified frequency for V_{LV} . The minimum operational V_{CC} is determined on the value of the voltage V_{LV} at the ambient temperature. The V_{LV} increases as the temperature decreases.
- 4. V_{CC} = 4.5V to 5.5V, typical values measured at V_{CC} = 5.0V
- 5. Standard Mode (not Low EMI Mode)
- 6. Z86E08 only
- 7. All outputs unloaded and all inputs are at V_{CC} or V_{SS} level.
- 8. If analog comparator is selected, then the comparator inputs must be at V_{CC} level.

AC ELECTRICAL CHARACTERISTICS

Timing Table (Standard Mode for SCLK/TCLK = XTAL/2) Standard Temperature

15				7	T _A = 0 °C	to +70 °C	•	<u></u>	
				8 N	8 MHz		MHz		
No	Symbol	Parameter	V _{cc}	Min	Max	Min	Max	Units	Notes
1	TpC	Input Clock Period	4.5V	125	DC	83	DC	ns	1
			5.5V	125	DC	83	DC	ns	1
2	TrC,TfC	Clock Input Rise	4.5V	-8.	25		15	ns	1
		and Fall Times	5.5V		25		15	ns	1
3	TwC	Input Clock Width	4.5V	62		41		ns	1
			5.5V	62		41	•	ns	1
4	TwTinL	Timer Input Low Width	4.5V	100		100		ns	1
			5.5V	70	1	70		ns	1
5	TwTinH	Timer Input High Width	4.5V	5TpC		5TpC			1
			5.5V	5TpC		5TpC			1
6	TpTin	Timer Input Period	4.5V		8TpC	8TpC		•••	1
			5.5V		8TpC	8TpC			1
7	TrTin,	Timer Input Rise	4.5V		100		100	ns	1
	TtTin	and Fall Time	5.5V		100		100	ns	1
8	TwlL	Int. Request Input	4.5V	70		70		ns	1,2
		Low Time	5.5V	70		70		ns	1,2
9	TwiH	Int. Request Input	4.5V		5TpC	5TpC			1,2
		High Time	5.5V		5TpC	5TpC		-	1,2
10	Twdt	Watch-Dog Timer	4.5V	12	<u> </u>	12		ms	1
		Delay Time for Timeout	5.5V	12	·	12	· ·	ms	1
11	Tpor	Power-On Reset Time	4.5V	20	80	20	80	ms	1
			5.5V	20	80	20	80	ms	1

Notes:

^{1.} Timing Reference uses 0.7 $\rm V_{CC}$ for a logic 1 and 0.2 $\rm V_{CC}$ for a logic 0.

^{2.} Interrupt request through Port 3 (P33-P31).

AC ELECTRICAL CHARACTERISTICS

Timing Table (Standard Mode for SCLK/TCLK = XTAL/2) Extended Temperature

				T 8 M		-			
No	Symbol	Parameter	V _{cc}	Min	Max	Min	Max	Units	Notes
1	ТрС	Input Clock Period	4.5V	125	DC	83	DC	ns	1
			5.5V	125	DC	83	DC	ns	1
2	TrC,TfC	Clock Input Rise	4.5V		25		15	ns	1
		and Fall Times	5.5V		25		15	ns	1
3	TwC	Input Clock Width	4.5V		62		41	ns	1
			5.5V		62		41	ns	1
4	TwTinL	Timer Input Low Width	4.5V	70		70		ns	1
			5.5V	70		70	•	ns	1
5	TwTinH	Timer Input High Width	4.5V	5TpC		5TpC			1
			5.5V	5TpC		5TpC			1
6	TpTin	Timer Input Period	4.5V	8TpC		8TpC			1
		<u> </u>	5.5V	8TpC		8TpC			1
7	TrTin,	Timer Input Rise	4.5V		100		100	ns	1
	TtTin	and Fall Time	5.5V		100		100	ns	1
8	TwlL	Int. Request Input	4.5V	70		70		ns	1,2
		Low Time	5.5V	70		70	•	ns	1,2
9	TwiH	Int. Request Input	4.5V	5TpC		5TpC			1,2
		High Time	5.5V	5TpC		5TpC			1,2
10	Twdt	Watch-Dog Timer	4.5V	10		10		ms	1
		Delay Time for Timeout	5.5V	10		10		ms	1
11	Tpor	Power-On Reset Time	4.5V	12	100	12	100	ms	1
			5.5V	12	100	12	100	ms	1

Notes:

^{1.} Timing Reference uses 0.7 $\rm V_{CC}$ for a logic 1 and 0.2 $\rm V_{CC}$ for a logic 0.

^{2.} Interrupt request made through Port 3 (P33-P31).

LOW NOISE VERSION

Low EMI Emission

The Z86E04/E08 can be programmed to operate in a Low EMI Emission Mode by means of a mask ROM bit option. Use of this feature results in:

- All pre-driver slew rates reduced to 10 ns typical.
- Internal SCLK/TCLK operation limited to a maximum of 4 MHz-250 ns cycle time.
- Output drivers have resistances of 500 Ohms (typical).
- Oscillator divide-by-two circuitry eliminated.

The Low EMI Mode is mask-programmable to be selected by the customer at the time the ROM code is submitted.

PIN FUNCTIONS

OTP Programming Mode

D7–D0 Data Bus. Data can be read from, or written to, the EPROM through this data bus.

 $V_{\rm CC}$ Power Supply. It is typically 5V during EPROM Read Mode and 6.4V during the other modes (Program, Program Verify, and so on).

CE Chip Enable (active Low). This pin is active during EPROM Read Mode, Program Mode, and Program Verify Mode.

OE Output Enable (active Low). This pin drives the Data Bus direction. When this pin is Low, the Data Bus is output. When High, the Data Bus is input.

EPM *EPROM Program Mode.* This pin controls the different EPROM Program Modes by applying different voltages.

 \mathbf{V}_{PP} Program Voltage. This pin supplies the program voltage.

Clear Clear (active High). This pin resets the internal address counter at the High Level.

Clock Address Clock. This pin is a clock input. The internal address counter increases by one with one clock cycle.

PGM Program Mode (active Low). A Low level at this pin programs the data to the EPROM through the Data Bus.

Application Precaution

The production test-mode environment may be enabled accidentally during normal operation if *excessive noise* surges above V_{CC} occur on the XTAL1 pin.

In addition, processor operation of Z8 OTP devices may be affected by *excessive noise* surges on the V_{pp} , \overline{CE} , EPM, \overline{OE} pins while the microcontroller is in Standard Mode.

Recommendations for dampening voltage surges in both test and OTP Mode include the following:

- Using a clamping diode to V_{CC}.
- Adding a capacitor to the affected pin.

Note: Programming the EPROM/Test Mode Disable option will prevent accidental entry into EPROM Mode or Test Mode.

PIN FUNCTIONS (Continued)

XTAL1, XTAL2 Crystal In, Crystal Out (time-based input and output, respectively). These pins connect a parallel-resonant crystal, LC, or an external single-phase clock (8 MHz or 12 MHz max) to the on-chip clock oscillator and buffer.

Port 0, P02—P00. Port 0 is a 3-bit bidirectional, Schmitt-triggered CMOS-compatible I/O port. These three I/O lines can be globally configured under software control to be inputs or outputs (Figure 7).

Auto Latch. The Auto Latch puts valid CMOS levels on all CMOS inputs (except P33, P32, P31) that are not externally driven. A valid CMOS level, rather than a floating node, reduces excessive supply current flow in the input buffer. On Power-up and Reset, the Auto Latch will set the ports to an undetermined state of 0 or 1. Default condition is Auto Latches enabled.

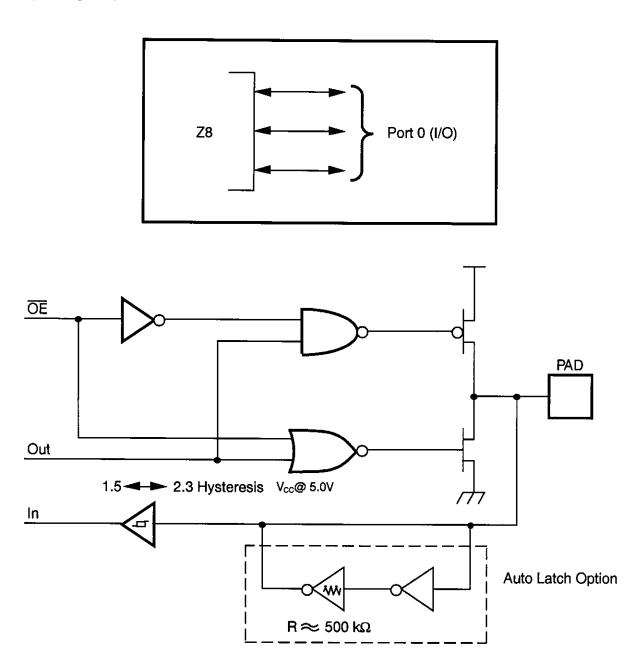


Figure 7. Port 0 Configuration

Comparator Inputs. Two analog comparators are added to input of Port 3, P31, and P32, for interface flexibility. The comparators reference voltage P33 (REF) is common to both comparators.

Typical applications for the on-board comparators; Zero crossing detection, A/D conversion, voltage scaling, and threshold detection. In Analog Mode, P33 input functions serve as a reference voltage to the comparators.

The dual comparator (common inverting terminal) features a single power supply which discontinues power in STOP

Mode. The common voltage range is 0–4 V when the $V_{\rm CC}$ is 5.0V; the power supply and common mode rejection ratios are 90 dB and 60 dB, respectively.

Interrupts are generated on either edge of Comparator 2's output, or on the falling edge of Comparator 1's output. The comparator output is used for interrupt generation, Port 3 data inputs, or T_{IN} through P31. Alternatively, the comparators can be disabled, freeing the reference input (P33) for use as IRQ1 and/or P33 input.

FUNCTIONAL DESCRIPTION

The following special functions have been incorporated into the Z8 devices to enhance the standard Z8 core architecture to provide the user with increased design flexibility.

RESET. This function is accomplished by means of a Power-On Reset or a Watch-Dog Timer Reset. Upon power-up, the Power-On Reset circuit waits for T_{POR} ms, plus 18 clock cycles, then starts program execution at address 000C (Hex) (Figure 10). The Z8 control registers' reset value is shown in Table 3.

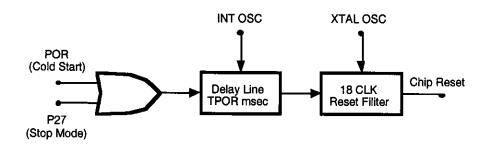


Figure 10. Internal Reset Configuration

Power-On Reset (POR). A timer circuit clocked by a dedicated on-board RC oscillator is used for a POR timer function. The POR time allows $V_{\rm CC}$ and the oscillator circuit to stabilize before instruction execution begins. The POR timer circuit is a one-shot timer triggered by one of the four following conditions:

- Power-bad to power-good status
- Stop-Mode Recovery
- WDT time-out
- WDH time-out

Watch-Dog Timer Reset. The WDT is a retriggerable one-shot timer that resets the Z8 if it reaches its terminal count. The WDT is initially enabled by executing the WDT instruction and is retriggered on subsequent execution of the WDT instruction. The timer circuit is driven by an on-board RC oscillator.

Program Memory. The Z86E04/E08 addresses up to 1K/2KB of Internal Program Memory (Figure 11). The first 12 bytes of program memory are reserved for the interrupt vectors. These locations contain six 16-bit vectors that correspond to the six available interrupts. Bytes 0–1024/2048 are on-chip one-time programmable ROM.

Identifiers 1023/2047 3FFH/7FFH Location of On-Chip First Byte of ROM Instruction Executed After RESET 12 0CH IRQ5 0BH 11 10 IRQ5 0AH IRQ4 9 09H IRQ4 8 08H 7 **IRQ3** 07H Interrupt Vector 6 06H IRQ3 (Lower Byte) IRQ2 5 05H 04H IRQ2 Interrupt Vector 3 IRQ1 03H (Upper Byte) IRQ1 2 02H 1 IRQ0 01H 0 00H IRQ0

Figure 11. Program Memory Map

Register File. The Register File consists of three I/O port registers, 124 general-purpose registers, and 14 control and status registers R0–R3, R4–R127 and R241–R255, respectively (Figure 12). General-purpose registers occupy the 04H to 7FH address space. I/O ports are mapped as per the existing CMOS Z8.

Location		Identifiers
255 (FFH)	Stack Pointer (Bits 7-0)	SPL
254 (FE)	General-Purpose Register	GPR
253 (FD)	Register Pointer	RP
252 (FC)	Program Control Flags	FLAGS
251 (FB)	Interrupt Mask Register	IMR
250 (FA)	Interrupt Request Register	IRQ
249 (F9)	Interrupt Priority Register	IPR
248 (F8)	Ports 0-1 Mode	P01M
247 (F7)	Port 3 Mode	РЗМ
246 (F6)	Port 2 Mode	P2M
245 (F5)	TO Prescaler	PRE0
244 (F4)	Timer/Counter 0	Τ 0
243 (F3)	T1 Prescaler	PRE1
242 (F2)	Timer/Counter 1	T1
241 (F1H)	Timer Mode	TMR
128	Not Implemented	
127 (7FH)	General-Purpose Registers	
4		
3	Port 3	P3
2	Port 2	P2
1	Reserved	P1
0 (00H)	Port 0	P0

Figure 12. Register File

FUNCTIONAL DESCRIPTION (Continued)

Table 5. Typical Frequency vs. RC Values V_{CC} = 5.0V @ 25°C

Load Capacitor										
	33	pFd	56	pFd	100	pFd	0.00 1μFd			
Resistor (R)	A(Hz)	B(Hz)	A(Hz)	B(Hz)	A(Hz)	B(Hz)	A(Hz)	B(Hz)		
1.0M	33K	31K	20K	20K	12K	11K	1.4K	1.4K		
560K	56K	52K	34K	32K	20K	19K	2.5K	2.4K		
220K	144K	130K	84K	78K	48K	45K	6K	6K		
100K	315K	270K	182K	164K	100K	95K	12K	12K		
56K	552K	480K	330K	300K	185K	170K	23K	22K		
20K	1.4M	1M	884K	740K	500K	450K	65K	61K		
10K	2.6M	2M	1.6M	1.3M	980K	820K	130K	123K		
5K	4.4M	3M	2.8M	2M	1.7K	1.3M	245K	225K		
2K	8M	5M	6M	4M	3.8K	2.7M	600K	536K		
1K	12M	7M	8.8M	6M	6.3K	4.2M	1.0M	950K		

Notes:

A = STD Mode Frequency. B = Low EMI Mode Frequency.

Table 6. Typical Frequency vs. RC Values V_{cc} = 3.3V @ 25°C

	Load Capacitor										
Resistor (R)	33 pFd		56 pFd		100	pFd	0.00 1μFd				
	A(Hz)	B(Hz)	A(Hz)	B(Hz)	A(Hz)	B(Hz)	A(Hz)	B(Hz)			
1.0M	18K	18K	12K	12K	7.4K	7.7K	1K	1K			
560K	30K	30K	20K	20K	12K	12K	1.6K	1.6K			
220K	70K	70K	47K	47K	30K	30K	4K	4K			
100K	150K	148K	97K	96K	60K	60K	8K	8K			
56K	268K	250K	176K	170K	100K	100K	15K	15K			
20K	690M	600K	463K	416K	286K	266K	40K	40K			
10K	1.2M	1M	860K	730K	540K	480K	80K	76K			
5K	2M	1.7M	1.5M	1.2M	950K	820K	151K	138K			
2K	4.6M	3M	3.3M	2.4M	2.2M	1.6M	360K	316K			
1K	7M	4.6M	5M	3.6M	3.6K	2.6M	660K	565K			

Notes:

A = STD Mode Frequency.

B = Low EMI Mode Frequency.

FUNCTIONAL DESCRIPTION (Continued)

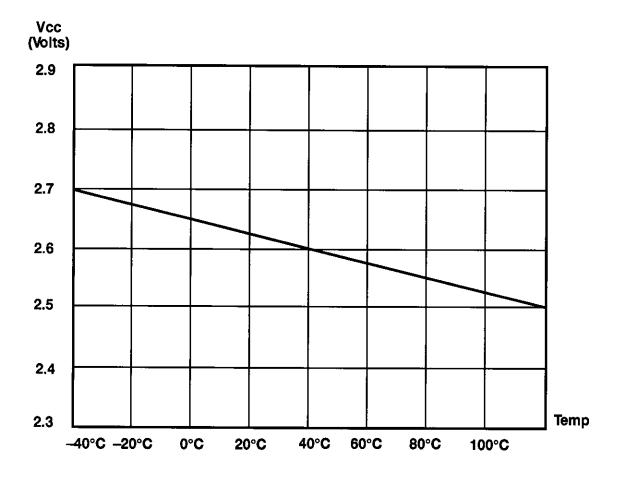


Figure 17. Typical Auto Reset Voltage (V_{LV}) vs. Temperature

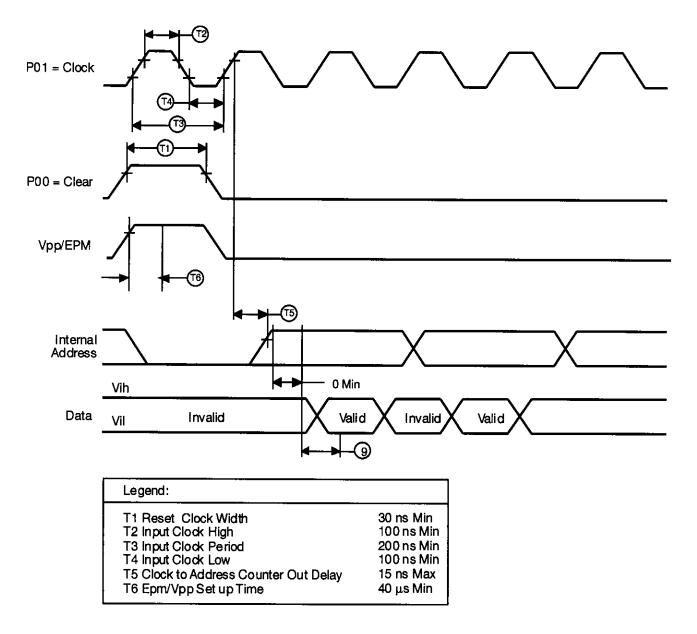


Figure 18. Z86E04/E08 Address Counter Waveform

FUNCTIONAL DESCRIPTION (Continued)

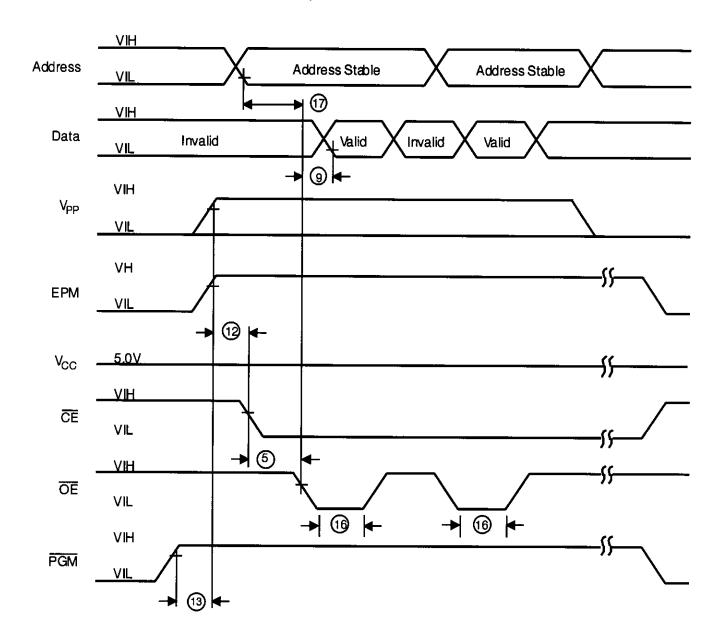


Figure 19. Z86E04/E08 Programming Waveform (EPROM Read)

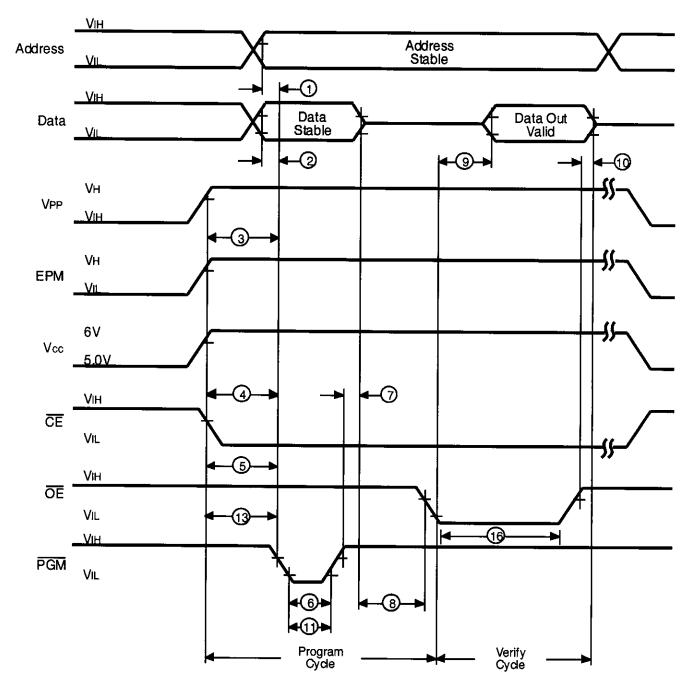


Figure 20. Z86E04/E08 Programming Waveform (Program and Verify)

Z8 CONTROL REGISTERS (Continued)

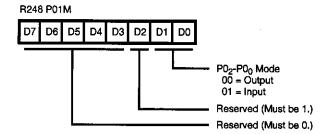


Figure 31. Port 0 and 1 Mode Register (F8_H: Write Only)

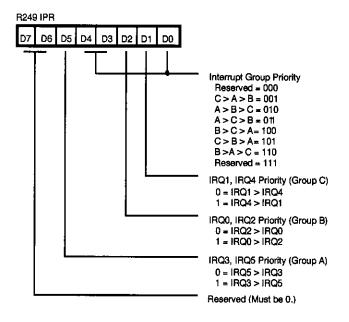


Figure 32. Interrupt Priority Register (F9_H: Write Only)

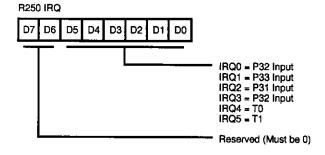


Figure 33. Interrupt Request Register (FA_H: Read/Write)

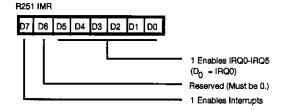


Figure 34. Interrupt Mask Register (FB_H: Read/Write)

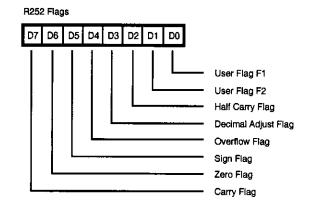


Figure 35. Flag Register (FC_H: Read/Write)

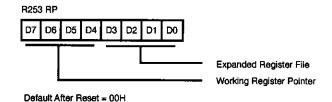


Figure 36. Register Pointer (FD_H: Read/Write)

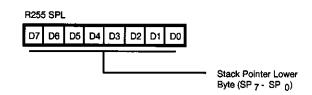
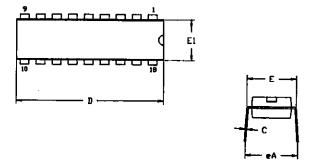
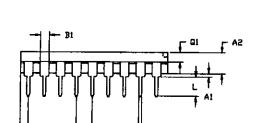


Figure 37. Stack Pointer (FF_H: Read/Write)

PACKAGE INFORMATION

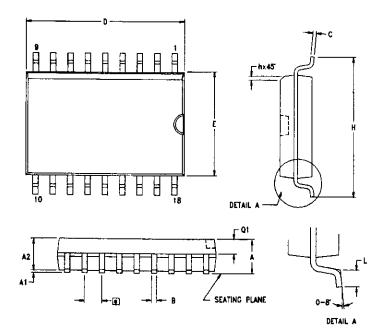




	MILLI	METER	INC	`H	
ZYMBOL	MIN	MAX	MIN	MAX	
Al	0.51	0.81	.020	.032	
SA	3.25	3.43	128	.135	
В	0.38	0.53	.015	.021	
Bl	1.14	1.65	.045	.065	
С	0.23	0.38	.009	.015	
D	22.35	23.37	.880	.920	
E	7.62	8.13	.300	.320	
El	6.22	6.48	.245	.255	
	2,54 TYP		.100	.100 TYP	
eA	7.87	8.89	.310	.350	
Ļ	3.18	3.81	.125	.150	
Qί	1.52	1.65	.060	.065	
2	0.89	1.65	.035	.065	

CONTROLLING DIMENSIONS : INCH

18-Pin DIP Package Diagram



SYMBOL	MILLIMETER		INCH	
	MIN	MAX	KIN	MAX
A	2.40	2.65	0.094	0.104
A1	0.10	0.30	0.004	0.012
A2	2.24	2.44	0.088	0.098
8	0.36	0.46	0.014	0.018
С	0.23	0.30	0.009	0.012
D	11.40	11.75	0.449	0.463
E	7.40	7.60	0.291	0.299
(1.27 TYP		0.050 TYP	
Н	10.00	10.65	0.394	0.419
h	0.30	0.50	0.012	0.020
_ L	0.60	1.00	0.024	0.039
Q1	0.97	1.07	0.038	0.042

CONTROLLING DIMENSIONS : MM LEADS ARE COPLANAR WITHIN .004 INCH.

18-Pin SOIC Package Diagram